



Type 2N2857 Geometry 0011 Polarity NPN

**Qual Level: JAN - JANS** 

**Generic Part Number:** 2N2857

REF: MIL-PRF-19500/343

## Features:

- Low power, ultra-high frequency transistor.
- Housed in TO-72 case.
- Also available in chip form using the 0011 chip geometry.
- The Min and Max limits shown are per MIL-PRF-19500/343 which Semicoa meets in all cases.

**Request Quotation** 



## **Maximum Ratings**

T<sub>C</sub> = 25°C unless otherwise specified

Rating	Symbol	Rating	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	15	V	
Collector-Base Voltage	V <sub>CBO</sub>	30	V	
Emitter-Base Voltage	$V_{EBO}$	3.0	V	
Collector Current, Continuous	I <sub>C</sub>	40	mA	
Operating Junction Temperature	$T_J$	-65 to +200	°C	
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C	



## **Electrical Characteristics**

 $T_C = 25^{\circ}C$  unless otherwise specified

OFF Characteristics	Symbol	Min	Max	Unit
Collector-Base Breakdown Voltage $I_C = 1 \mu A$	V <sub>(BR)CBO</sub>	30		V
Collector-Emitter Breakdown Voltage $I_C = 3 \text{ mA}$	V <sub>(BR)CEO</sub>	15		V
Emitter-Base Breakdown Voltage $I_E = 10 \mu A$	V <sub>(BR)EBO</sub>	3.0		V
Collector-Emitter Cutoff Current $V_{CB} = 15 \text{ V}$	I <sub>CES</sub>		100	nA
Collector-Base Cutoff Current $V_{CB} = 15 \text{ V}$	I <sub>CBO</sub>		10	nA

ON Characteristics	Symbol	Min	Max	Unit
Collector-Emitter Saturation Voltage $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$	$V_{CE(sat)}$		0.4	V dc
Base-Emitter Saturation Voltage $I_C = 150 \text{ mA}, I_B = 1 \text{ mA}$	$V_{BE(sat)}$		1.0	V dc

Small Signal Characteristics	Symbol	Min	Max	Unit
Forward Current Transfer Ratio				
$I_C = 3 \text{ mA}, V_{CE} = 1 \text{ V}$	$h_{FE}$	30	150	
$I_C = 2 \text{ mA}$ , $V_{CE} = 6 \text{ V}$ , case lead floating	h <sub>FE</sub>	50	220	
Magnitude of Common Emitter Short Circuit Forward Current Transfer Ratio $V_{CE} = 6 \text{ V}, I_{C} = 5 \text{ mA}, f = 100 \text{ MHz}$	h <sub>FE</sub>	10	21	
Small Signal Power Gain	$G_{PE}$	12.5	21	dB
Collector-Base Feedback Capacitance V <sub>CB</sub> = 10 V, I <sub>E</sub> = 2 mA, 100 kHz < f < 1 MHz	$C_{CB}$		1.0	pF
Collector-Base Time Constant $V_{CE} = 6 \text{ V}, I_E = 2 \text{ mA}, f = 31.9 \text{ MHz}$	$r_{b'}C_C$	4.0	15	ps
Noise Figure $V_{CE} = 6 \text{ V}, I_{C} = 1.5 \text{ mA,rg} = 50 \text{ ohms}, 450 \text{ MHz}$	NF		4.5	dB